

Fast Recovery Diodes

FEATURES

- High surge capability
- Qualified for industrial level
- International standard case DO-205AB
- Both metric and inch threads

TYPICAL APPLICATIONS

- Power supplies
- Machine tools control
- High power drives
- Welders
- Medium traction

MAJOR RATINGS AND CHARACTERISTICS			
PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{F(AV)}$		240	A
	T_{Case}	100	°C
$I_{F(RMS)}$		380	A
	T_{Case}	100	°C
I_{FSM}	50 Hz	6560	A
	60 Hz	7150	A
I^2t	50 Hz	195	kA ² s
	60 Hz	213	kA ² s
V_{DRM}/V_{RRM}		200 to 1600	V
T_J		-40 to 150	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
SERIES	VOLTAGE CODE	V_{DRM}/V_{RRM} , MAX. RE- PETITIVE PEAK AND OFF-STATE VOLTAGE (V)	V_{RSM} , MAX. NON- REPETITIVE PEAK VOLTAGE (V)	I_{DRM}/I_{RRM} , MAX. at T_J = $T_{J(Max.)}$ (mA)
DF240/...10	02	200	300	100
DF240/...10	04	400	500	
DF240/...10	06	600	700	
DF240/...10	08	800	900	
DF240/...10	10	1000	1100	
DF240/...10	12	1200	1300	
DF240/...10	14	1400	1500	
DF240/...10	16	1600	1700	

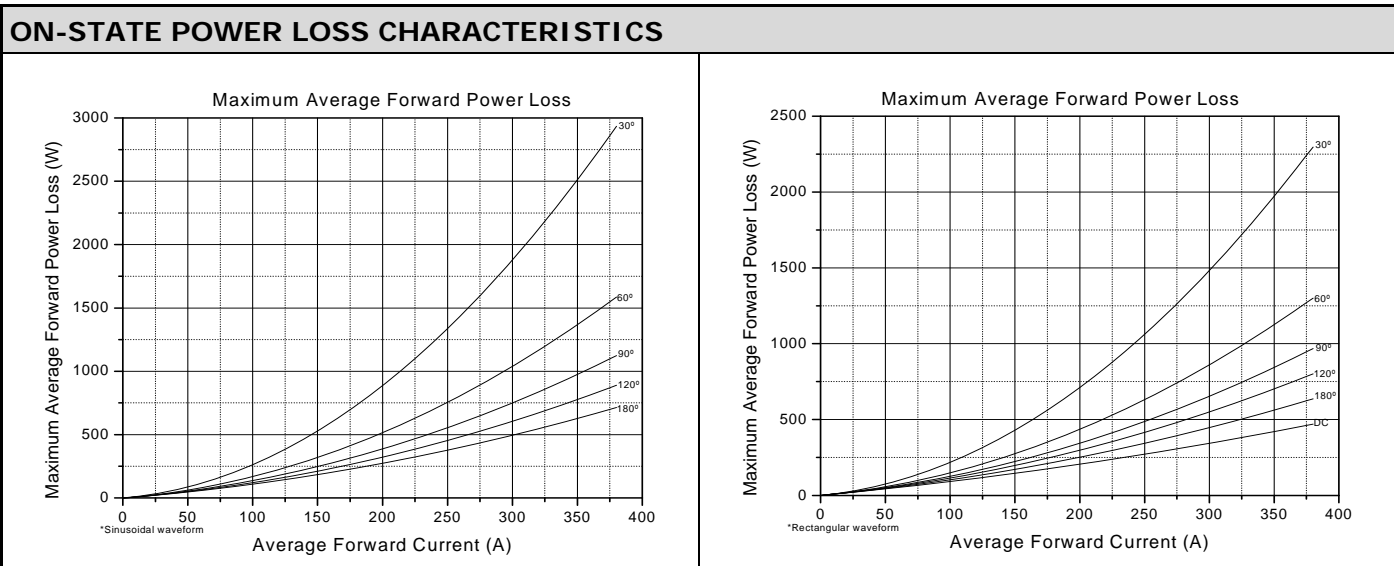
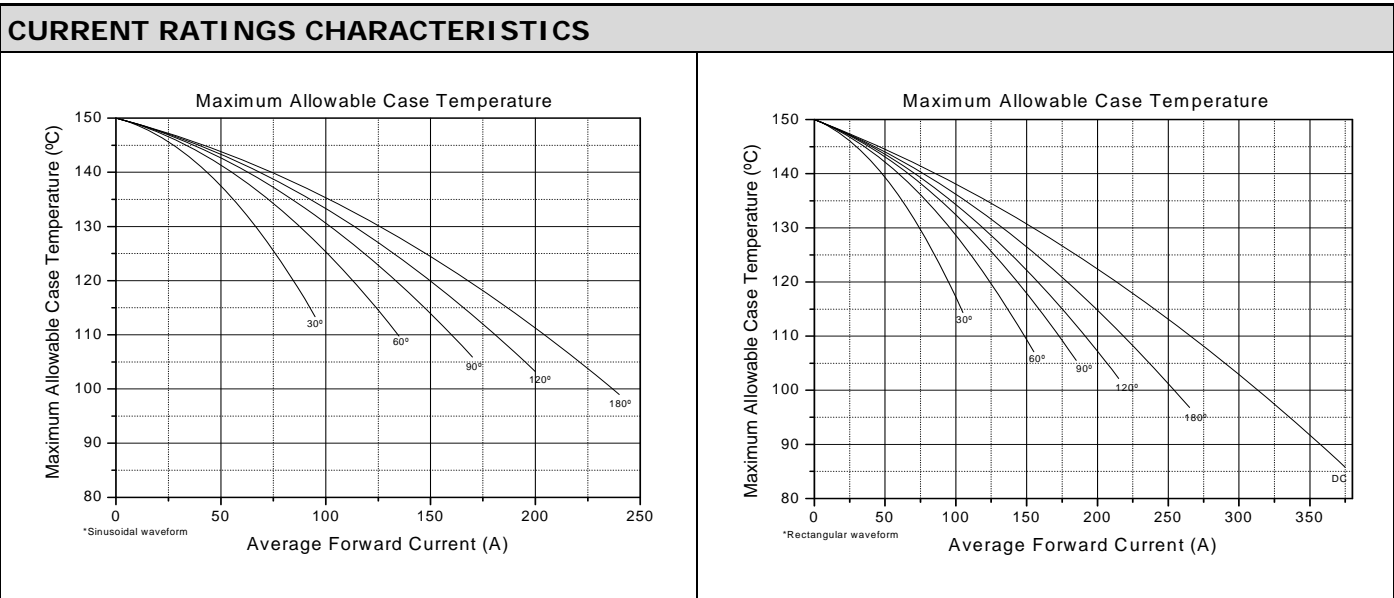
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MAXIMUM ALLOWABLE RATINGS					
SYMBOL	DESCRIPTION	TEST CONDITIONS		VALUE	UNITS
$I_{F(AV)}$	Maximum average on-state current at heatsink temperature	180° conduction, half sine wave		240	A
				100	°C
$I_{F(RMS)}$	Maximum RMS on-state current	DC at 25°C heatsink temperature		380	A
I_{FSM}	Maximum peak, one-cycle non-repetitive surge current	t = 10 ms	100% V_{RRM} reapplied	Sinusoidal half wave, initial $T_J = T_J \text{ max.}$	kA
		t = 8.3 ms			
		t = 10 ms	No voltage reapplied		
		t = 8.3 ms			
I^2t	Maximum I^2t	t = 10 ms	100% V_{RRM} reapplied		kA ² s
		t = 8.3 ms			
		t = 10 ms	No voltage reapplied		
		t = 8.3 ms			
$I^2t^{1/2}$	Maximum $I^2t^{1/2}$	t = 0.1 to 10 ms, no voltage reapplied		2340	kA ² s ^{1/2}
$I_{RM(REC)}$	Peak reverse recovery current	-		50	A
I_{RM}	Peak reverse current	-		100	mA
I_{FM}	Peak forward current	-		240	A
di/dt	Max.non-rep. rate of rise of current	$T_J = 25^\circ\text{C}, V_D = V_{DRM}, I_{FM} = 1\text{A}$		50	A/ μs
t_{rr}	Max.reverse recovery time	$T_J = 25^\circ\text{C}, I_{FM} = 1\text{A}, V_R = 30\text{V}, -di_F/dt = 25\text{A}/\mu\text{s}$		1000	ns
		$T_J = 25^\circ\text{C}, -di_F/dt = 25\text{A}/\mu\text{s}, I_{FM} = \pi \times \text{rated } I_{F(AV)}$		2000	ns
$V_{F(TO)}$	Low level threshold voltage	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}), T_J = T_J \text{ max.}$		0.80	V
r_F	Low level on-state slope resistance			1.15	m Ω
V_{FM}	Maximum on-state voltage	$I_{pk} = 754\text{A}, 50\text{Hz half sine pulse}, T_J = T_J \text{ max.}$		1.75	V

THERMAL AND MECHANICAL SPECIFICATIONS				
SYMBOL	DESCRIPTION	TEST CONDITIONS	VALUE	UNITS
T_J	Maximum operating junction temperature	-	-40 to 150	°C
T_{Stg}	Maximum storage temperature	-	-40 to 150	
R_{thJ-hs}	Maximum thermal resistance, junction to heatsink	DC	0.20	°C/W
		180° sine wave	0.22	
		120° rectangular wave	0.24	
R_{thC-hs}	Maximum thermal resistance, case to heat-sink	Mtg. Surface smooth, flat, greased	0.03	
-	Mounting force, $\pm 10\%$	-	30	N.m
-	Approximate weight	-	250	g
-	Case style	-	DO-205AB	JEDEC

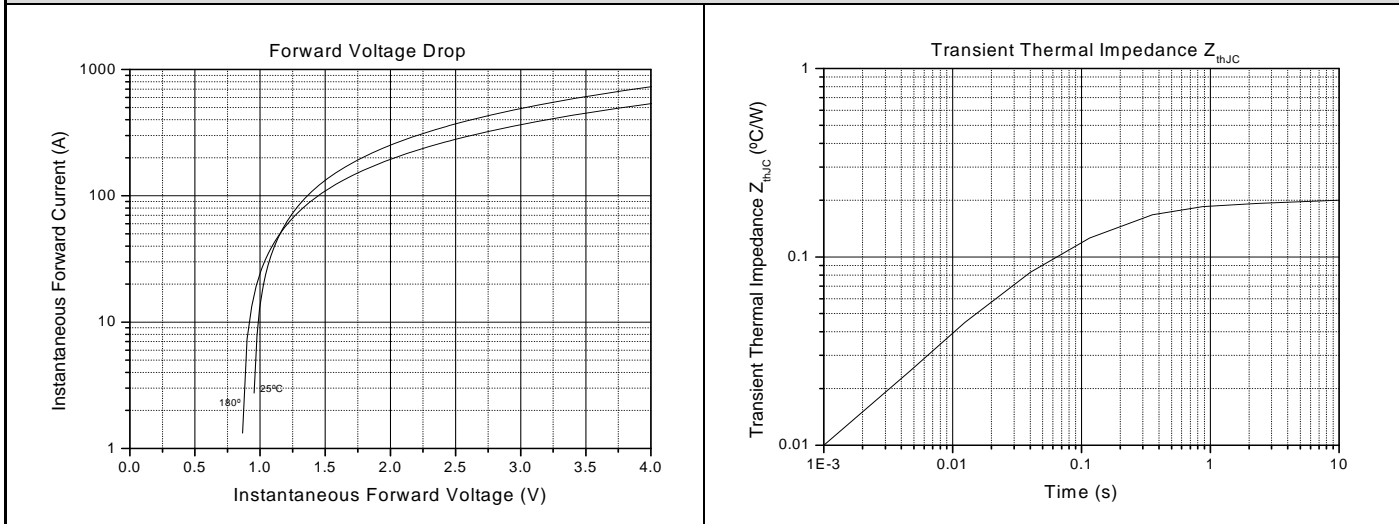
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CURRENT FORM FACTOR								
FORM FACTOR	CONDUCTION ANGLE	15°	30°	45°	60°	90°	120°	180°
Sine wave		31.956	15.832	10.452	7.721	4.933	3.527	2.468
Rectangular wave		24.000	12.000	8.000	6.000	4.000	3.000	2.000

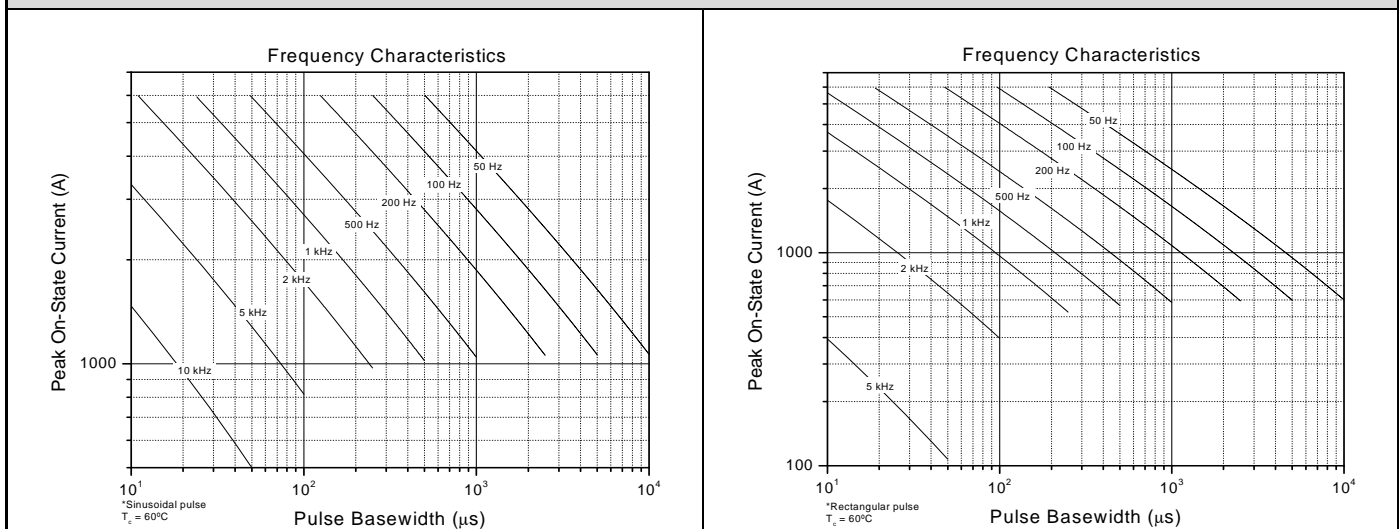


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FORWARD VOLTAGE DROP / THERMAL IMPEDANCE CHARACTERISTICS

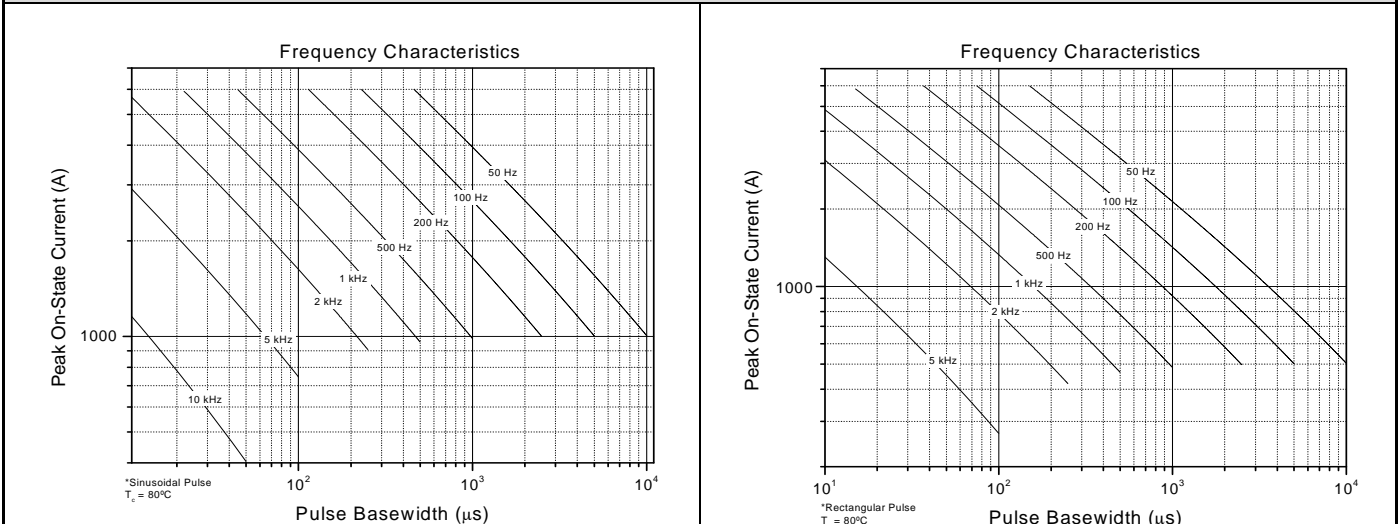


FREQUENCY CHARACTERISTICS

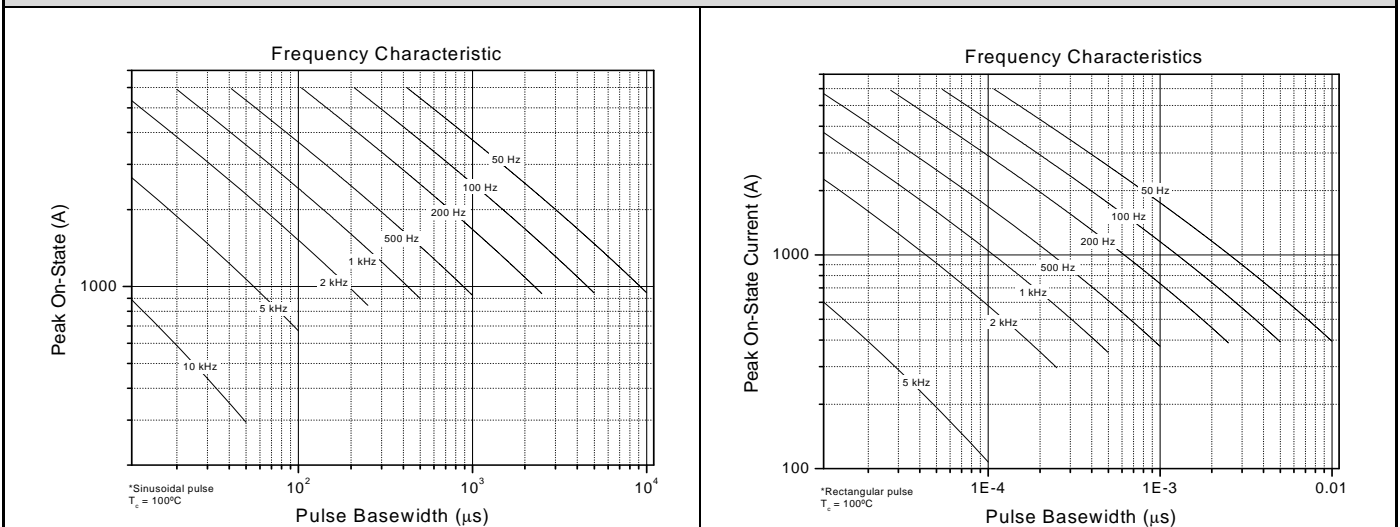


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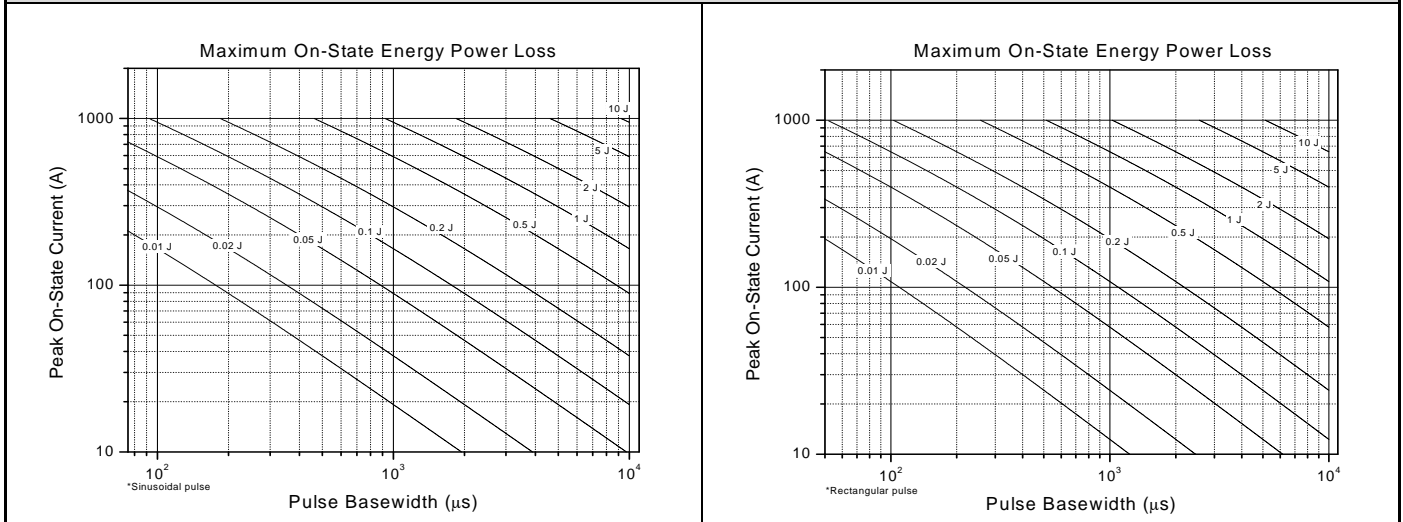


FREQUENCY CHARACTERISTICS

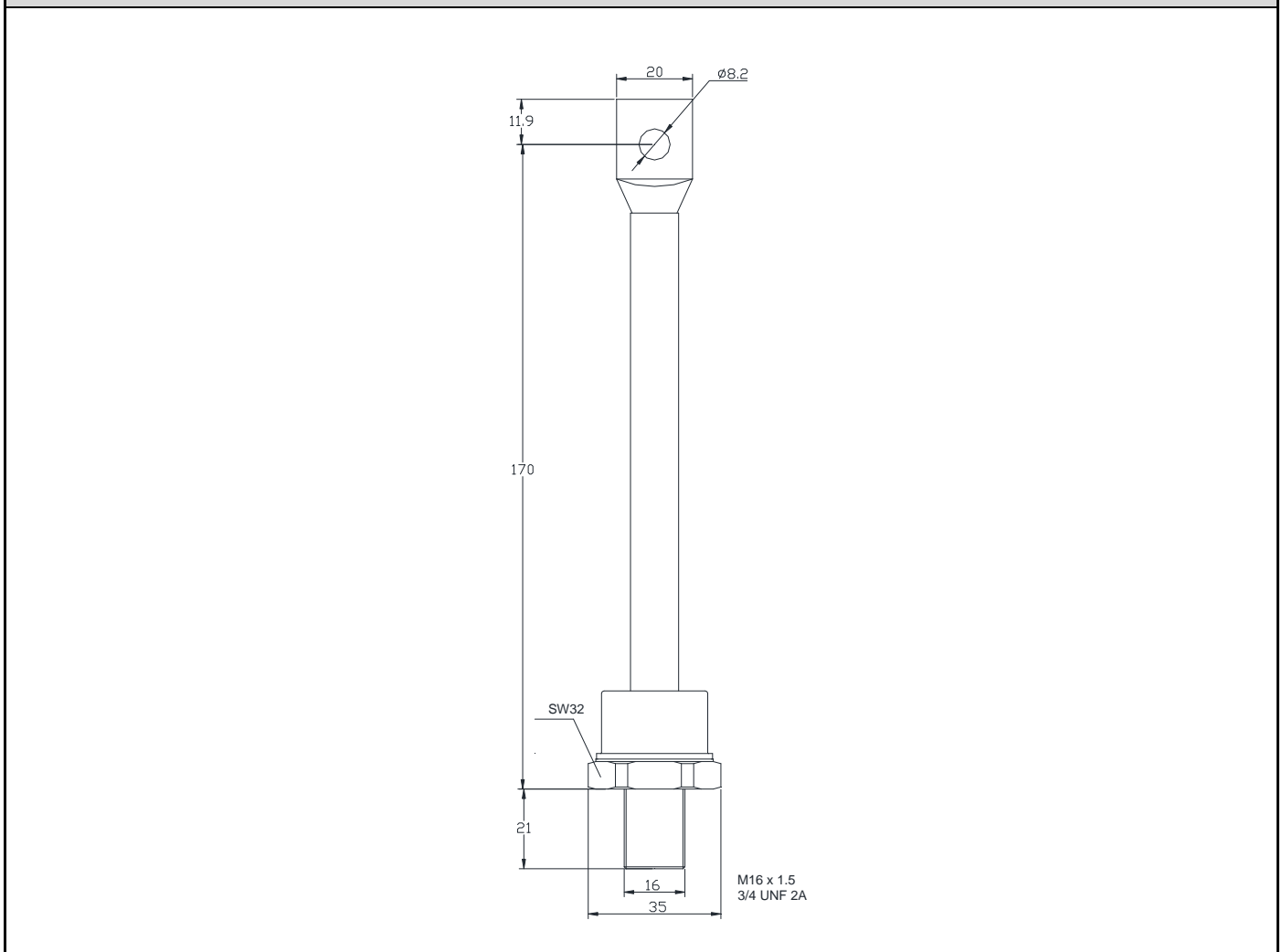


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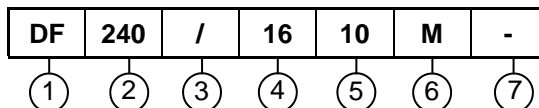
MAXIMUM ON-STATE POWER LOSS CHARACTERISTICS



OUTLINE CHARACTERISTICS



Fast Recovery Diodes

ORDERING INFORMATION
Device code


- | | |
|---|--|
| 1 | <ul style="list-style-type: none"> - N = Phase Control Thyristors - F = Fast Thyristors (inverter grade) - D = Normal Recovery Diodes - DF = Fast Recovery Diodes - DD = Module (diode-diode) - DT = Module (diode-thyristor) - TD = Module (thyristor-diode) - TT = Module (thyristor-thyristor) - P = Press-fit diode |
| 2 | <ul style="list-style-type: none"> - Average Current Code |
| 3 | <ul style="list-style-type: none"> - Essential Part Number |
| 4 | <ul style="list-style-type: none"> - Voltage Code x 100 = V_{RRM} |
| 5 | <ul style="list-style-type: none"> - Turn-off time (fast thyristors only) - Reverse Recovery Time (fast diodes only) |
| 6 | <ul style="list-style-type: none"> - M = Metric Thread - I = Inch Thread |
| 7 | <ul style="list-style-type: none"> - None = Anode to stud (stud diodes only) - R = Cathode to stud (stud diodes only) |

Disclaimer

All product specifications and data are subject to change without notice.

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